TOSHIBA Transistor Silicon NPN Epitaxial Type

# 2SC5376

### Audio Frequency General Purpose Amplifier Applications For Muting and Switching Applications

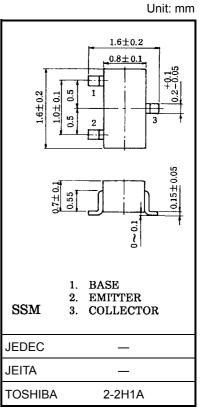
- Low collector saturation voltage: VCE (sat) (1) = 15 mV (typ.)

 $@I_{C} = 10 \text{ mA/I}_{B} = 0.5 \text{ mA}$ 

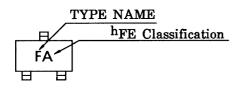
• High collector current: IC = 400 mA (max)

#### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V <sub>CBO</sub>	15	V	
Collector-emitter voltage	V <sub>CEO</sub>	12	V	
Emitter-base voltage	V <sub>EBO</sub>	5	V	
Collector current	Ι <sub>C</sub>	400	mA	
Base current	Ι <sub>Β</sub>	50	mA	
Collector power dissipation	P <sub>C</sub>	100	mW	
Junction temperature	Тј	125	°C	
Storage temperature range	T <sub>stg</sub>	-55~125	°C	



### Marking



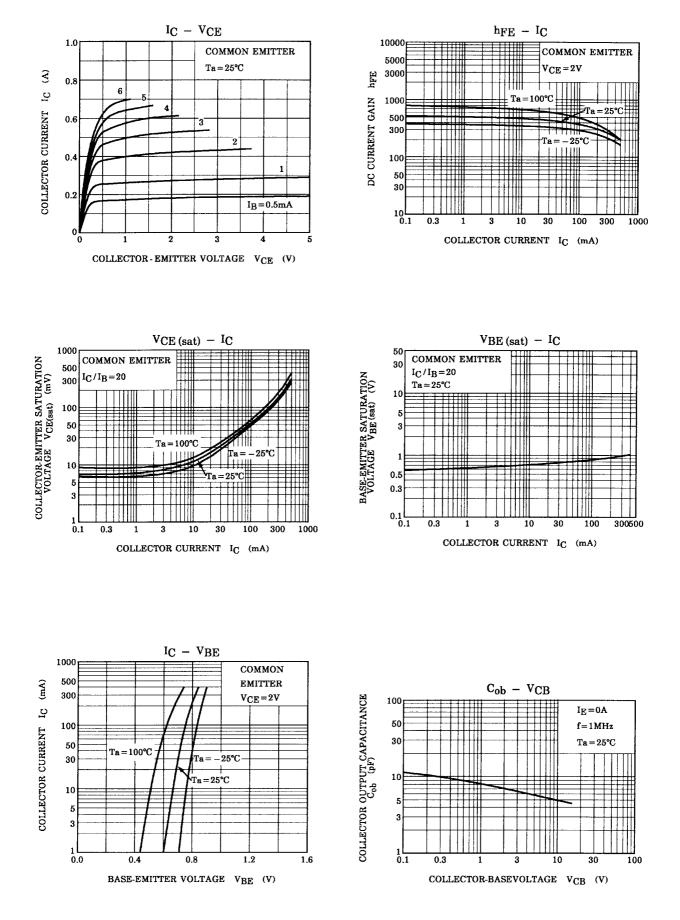
Weight: 2.4 mg (typ.)

Electrical Characteristics (Ta = 25°C)

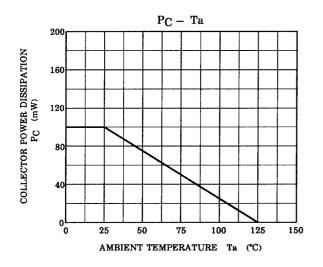
Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off c	current	I <sub>CBO</sub>	$V_{CB} = 15 \text{ V}, \text{ I}_{E} = 0$			0.1	μA
Emitter cut-off cu	rrent	I <sub>EBO</sub>	$V_{EB} = 5 V, I_{C} = 0$	_		0.1	μA
DC current gain		h <sub>FE</sub> (Note)	$V_{CE} = 2 \text{ V}, \text{ I}_{C} = 10 \text{ mA}$	300	_	1000	
Collector-emitter saturation voltage		V <sub>CE (sat)</sub> (1)	$I_{C} = 10 \text{ mA}, I_{B} = 0.5 \text{ mA}$		15	30	mV
		V <sub>CE (sat)</sub> (2)	$I_{C} = 200 \text{ mA}, I_{B} = 10 \text{ mA}$	_	110	250	
Base-emitter volta	age	V <sub>BE (sat)</sub>	$I_{C} = 200 \text{ mA}, I_{B} = 10 \text{ mA}$	_	0.87	1.2	V
Transition frequency		f <sub>T</sub>	$V_{CE} = 2 V, I_{C} = 10 mA$	80	130		MHz
Collector output capacitance		C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1 \text{ MHz}$		4.2		pF
Collector-emitter on resistance		R <sub>on</sub>	$I_B = 1 \text{ mA}, V_{in} = 1 V_{rms}, f = 1 \text{ kHz}$	_	0.9		Ω
	Turn-on time	t <sub>on</sub>		_	85		
	Storage time	t <sub>stg</sub>	$ \begin{array}{c} 0 \\ \downarrow \downarrow \\ 10 \\ \mu s \end{array} $ $ \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\$	_	170		ns
	Fall time	t <sub>f</sub>	= -3V = 6V Duty cycle $\leq 2\%$ $I_{B1} = -I_{B2} = 5 \text{ mA}$		40		

Note: h<sub>FE</sub> classification A: 300~600, B: 500~1000

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